TOSHIBA Photocoupler IRED & Photo-Transistor

# TLP627, TLP627-2, TLP627-4

Programmable Controllers
DC-output Module
Telecommunication

The TOSHIBA TLP627,-2 and -4 consist of an infrared emitting diode optically coupled to a Darlington connected phototransistor which has an integral base-emitter resistor to optimize switching speed and elevated temperature characteristics.

The TLP627-2 offers two isolated channels in eight lead plastic DIP, while the TLP627-4 provide four isolated channels per package.

Collector-Emitter Voltage : 300 V (min)Current Transfer Ratio : 1000 % (min)

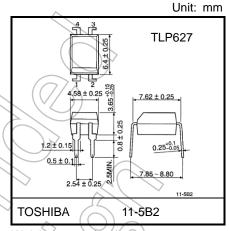
UL-recognized : UL 1577, File No.E67349

cUL-recognized : CSA Component Acceptance Service

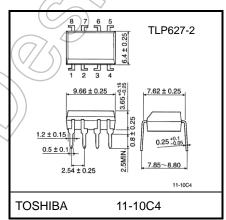
No.5A File No.E67349

VDE-approved : EN 60747-5-5 (Note 1)

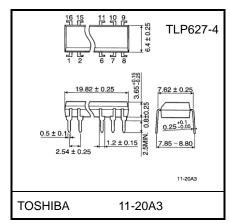
Note 1: When a VDE approved type is needed, please designate the **Option(D4)**.



Weight: 0.26 g (typ.)



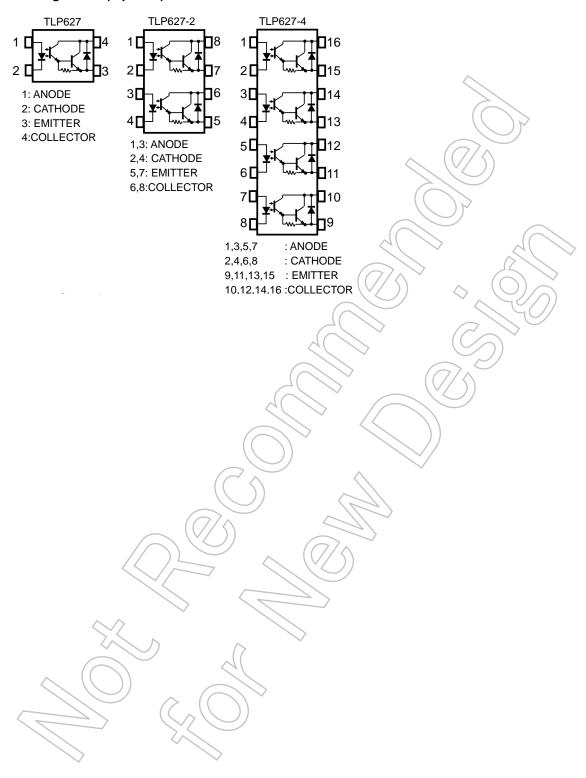
Weight: 0.54 g (typ.)



Weight: 1.1 g (typ.)

Start of commercial production 1984-08

### Pin Configuration (top view)



### Absolute Maximum Ratings (Ta=25°C)

Characteristics			Ratin		
		Symbol	TLP627	TLP627-2 TLP627-4	Unit
	Forward Current	lF	60	50	mA
	Forward Current Derating	ΔIF /°C	-0.7(Ta≥39°C)	-0.5(Ta≥25°C)	mA /°C
Ω	Pulse Forward Current	IFP	1 (100µs pulse,100pps)		Α
핔	Reverse Voltage	V <sub>R</sub>	5		V
	Diode Power Dissipation (1 Circuit)	PD	100	70	mW
	Diode Power Dissipation Derating (1 Circuit)	Δ P <sub>D</sub> /°C	-1.2 (Ta≥39°C)	-0.7 (Ta≥25°C)	mW /°C
	Collector-Emitter Voltage	VCEO	300		V
jo	Emitter -Collector Voltage	VECO	0.3		٧
Detector	Collector Current	Ic 🗸	150		mA
Δ	Collector Power Dissipation (1 Circuit)	Pc	150(300(Note 1))	100	mW
	Collector Power Dissipation Derating (Ta≥25°C,1 Circuit)	∆ P¢ /°¢	-1.5(-3.5(Note 1))	-1.0	mW /°C
Operating Temperature Range		Topr	-55 to 100		°C
Storage Temperature Range		T <sub>stg</sub>	-55 to 125		°C
Lead Soldering Temperature		T <sub>sol</sub>	260(10 s)		°C
Tota	al Package Power Dissipation (1 Circuit)	Рт	250(320(Note 1))	150	mW
Total Package Power Dissipation Derating (Ta≥25°C,1 Circuit)		∆ P <sub>T</sub> /°C	-2.5(-3.2(Note 1))	-1.5	mW /°C
Isola	ation Voltage (AC,60 s, R.H. ≤ 60 %) (Note 2)	BVs	5000	)	Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: I<sub>F</sub>=20 mA Max

Note 2: Device considered a two terminal device : LED side pins Shorted together and DETECTOR side pins shorted together.

### **Recommended Operating Conditions**

Characteristics	Symbol	Min	Тур.	Max	Unit
Supply Voltage	Vcc	-	_	200	V
Forward Current	(JF)	_	16	25	mA
Collector Current	1c	_	_	120	mA
Operating Temperature	Topr	-25	_	85	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

### **Electrical Characteristics (Ta=25°C)**

	Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
	Forward Voltage	VF	I <sub>F</sub> = 10 mA	1.0	1.15	1.3	V
LED	Reverse Current	IR	V <sub>R</sub> = 5 V		_	10	μΑ
	Capacitance	Ст	V = 0 V, f = 1MHz	_<	30	-	pF
	Collector-Emitter Breakdown Voltage	V(BR)CEO	I <sub>C</sub> = 0.1mA	300 (			V
tor	Emitter-Collector Breakdown Voltage	V <sub>(BR)ECO</sub>	I <sub>E</sub> = 0.1mA	0.3	> ((	_	V
Detector	Collector Dark Current		VCE = 200V	, YY	)10	200	nA
	Collector Dark Current	ICEO	V <sub>CE</sub> = 200V, Ta = 85 °C	1		20	μA
	Capacitance Collector to Emitter	C <sub>CE</sub>	V = 0 V, f = 1MHz	<b>)</b>	10	) [	pF

# Coupled Electrical Characteristics (Ta=25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Current Transfer Ratio	IC/IF	IF = 1 mA, VCE = 1 V	1000	4000	_	%
Saturated CTR	Ic/IF(sat)	IF = 10 mA, VCE = 1 V	500	1	_	%
Collector-Emitter	Vor(cot)	IC = 10 mA, IF = 1 mA		_	1.0	V
Saturation Voltage	VCE(sat)	IC = 100 mA, IF = 10 mA	0.3		1.2	V

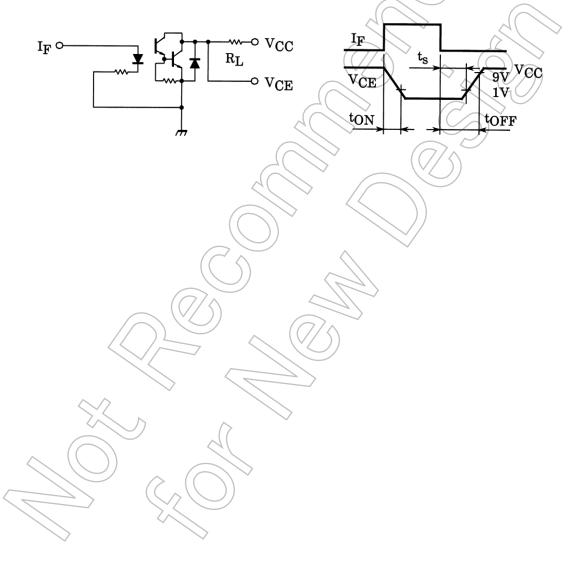
# Isolation Electrical Characteristics (Ta=25°C)

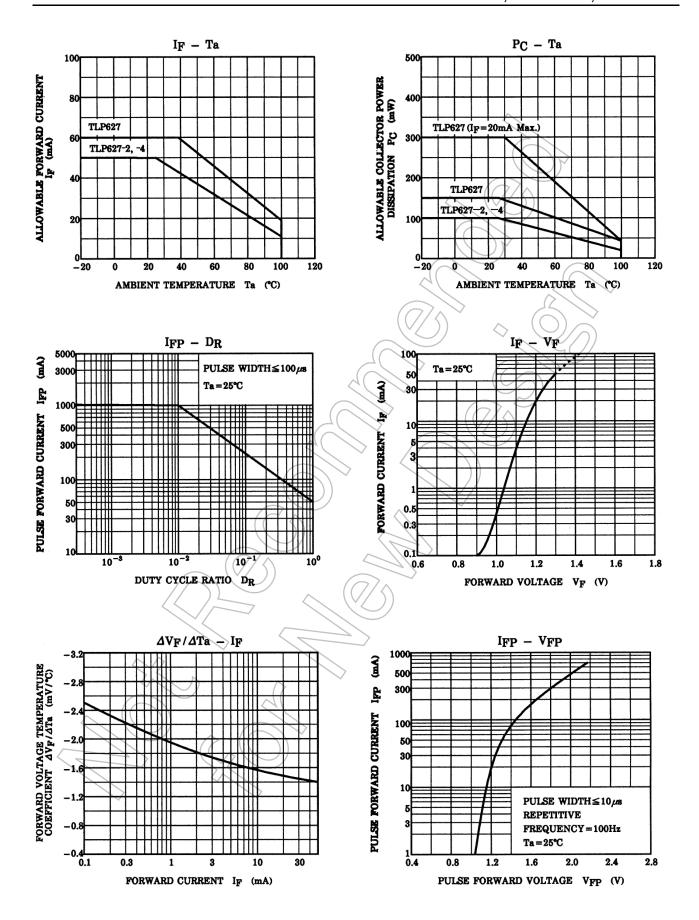
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Capacitance Input to Output	Cs	$V_S = 0 V, f = 1 MHz$	_	0.8	_	pF
Isolation Resistance	7 Rs	V <sub>S</sub> = 500 V, R.H .≤ 60 %	5×10 <sup>10</sup>	10 <sup>14</sup>	_	Ω
Isolation Voltage	BVs	AC, 60 s	5000	_	1	Vrms

### **Switching Characteristics (Ta=25°C)**

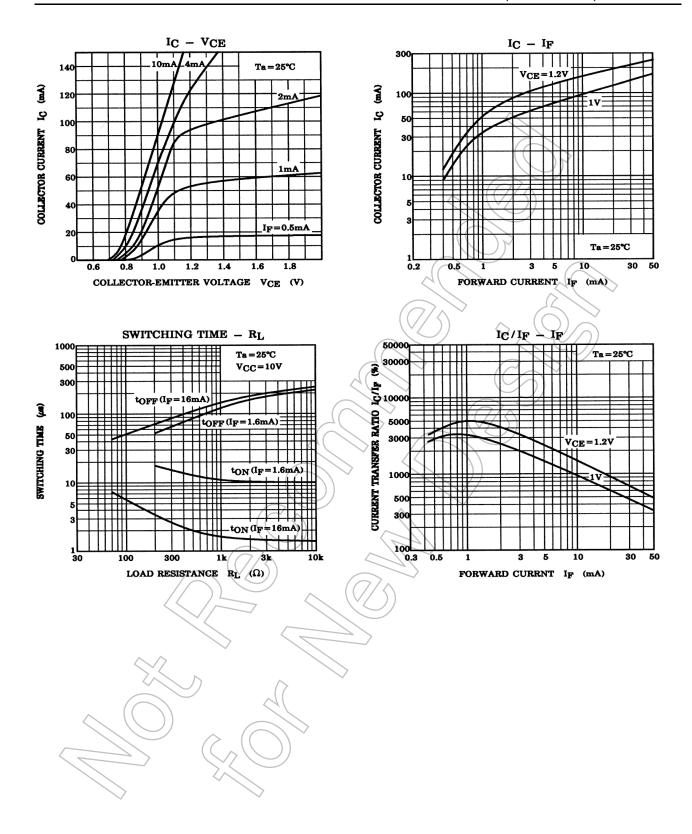
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Rise Time	t <sub>r</sub>		_	40	_	
Fall Time	tf	$V_{CC} = 10 \text{ V}$ $I_{C} = 10 \text{ mA}$ $R_{L} = 100 \Omega$	_	15	_	
Turn-on Time	ton		- <	50	_	
Turn-off Time	t <sub>off</sub>	_	- (	15	_	μs
Turn-on Time	toN	R <sub>L</sub> = 180 $\Omega$ (Fig.1) V <sub>CC</sub> = 10 V, I <sub>F</sub> = 16 mA	- \	5	)'-	
Strage Time	ts		60)	40	_	
Turn-off Time	toff		/ //	80	_	

Fig.1 Switching Time Test Circuit

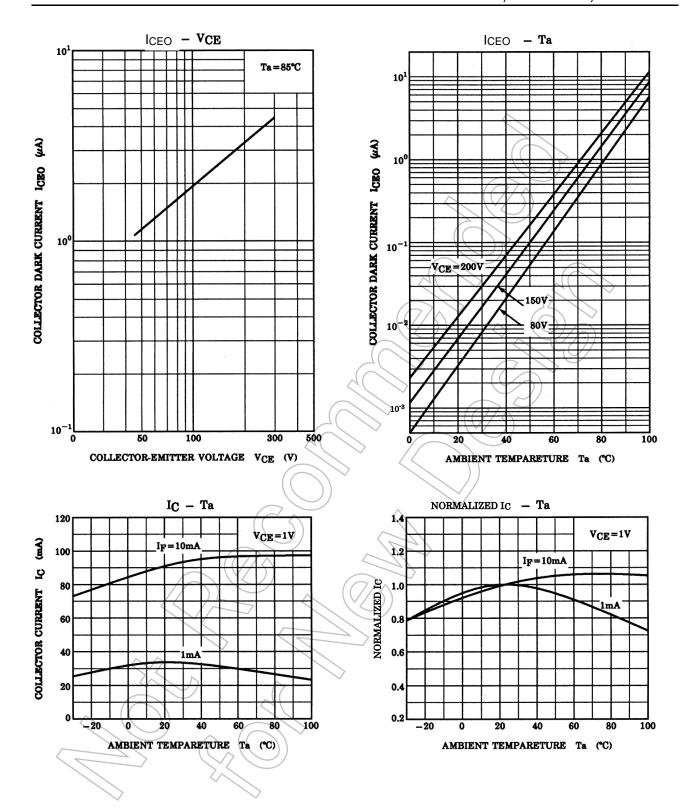




NOTE: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



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